

ADE-208-071 B (Z)

# HVU314

## Variable Capacitance Diode for BS tuner

# HITACHI

Preliminary  
Rev. 2  
Mar. 1994

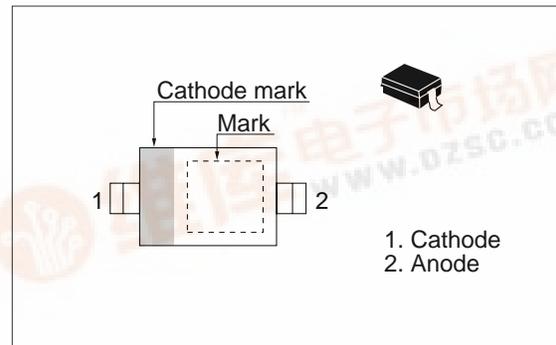
### Features

- Low series resistance. ( $r_s=1.05\Omega$  max)
- Ultra small Resin Package (URP) is suitable for surface mount design.

### Ordering Information

Type No.	Laser Mark	Package Code
HVU314	P	URP

### Outline



### Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Value	Unit
Reverse voltage	$V_R$	32	V
Junction temperature	$T_j$	125	°C
Storage temperature	$T_{stg}$	-55 to +125	°C

### Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse current	$I_{R1}$	—	—	10	nA	$V_R = 32$ V
	$I_{R2}$	—	—	100		$V_R = 32$ V, $T_a = 60$ °C
Capacitance	$C_1$	4.40	—	6.40	pF	$V_R = 1$ V, $f = 1$ MHz
	$C_{10}$	0.86	—	1.35		$V_R = 10$ V, $f = 1$ MHz
	$C_{30}$	0.47	—	0.73		$V_R = 30$ V, $f = 1$ MHz
Capacitance ratio	n	7.0	—	—	—	$C_1 / C_{30}$
Series resistance	$r_s$	—	—	1.05	$\Omega$	$V_R = 5$ V, $f = 470$ MHz
Matching error	$\Delta C/C^*$	—	—	6.0	%	$V_R = 1 \sim 30$ V

\* A set of HVU314 is of uniform C-V characteristics.

Measure max. value and min. value of capacitance at each bias point of  $V_R=1$ V and 30V.

Calculate Matching Error, 
$$\Delta C/C = \frac{(C_{max}-C_{min})}{C_{min}} \times 100 (\%)$$

\*\* Each group shall uniform a multiple of 4 diodes.



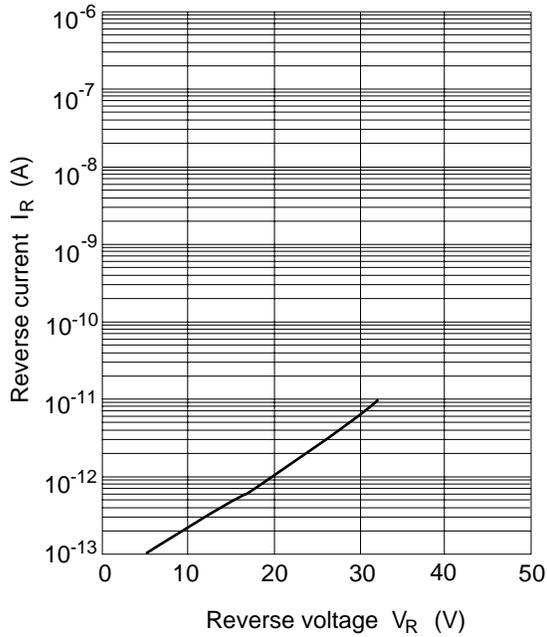


Fig.1 Reverse current Vs. Reverse voltage

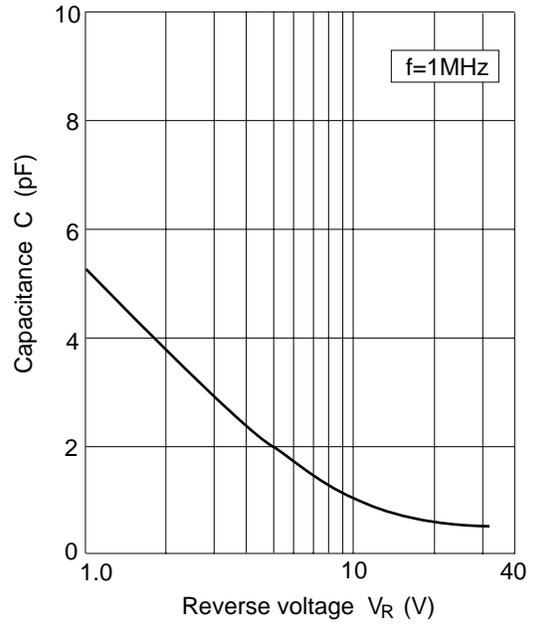


Fig.2 Capacitance Vs. Reverse voltage

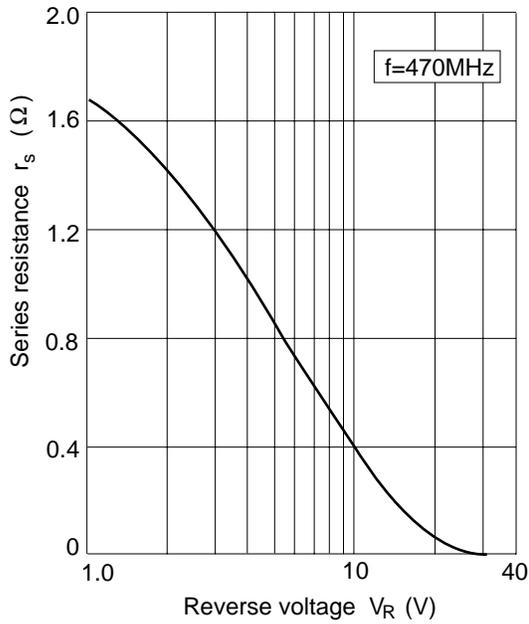


Fig.3 Series resistance Vs. Reverse voltage

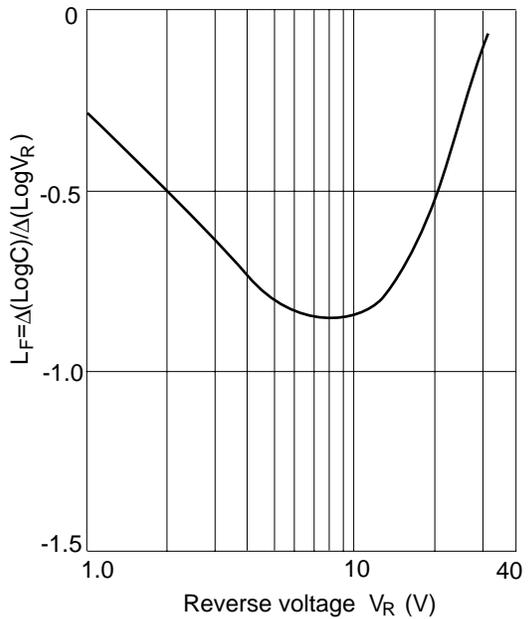


Fig.4 Linearity factor Vs. Reverse voltage

Package Dimensions

Unit: mm

